RICOH

100 mA Ultra-low Supply Current (0.3 µA) LDO Regulator with Battery Monitor

No. EA-503-191025

OVERVIEW

The RP124x is an LDO regulator with a battery monitor (BM) featuring ultra-low supply current. The battery monitor has a function which divides the input voltage (V_{IN}) into 1/3 or 1/4. The battery charge remaining can be monitored by MCU. The buffering output enables directly inputting a signal into the low voltage A/D converter (ADC) with built-in MCU.

KEY BENEFITS

- Achieving Low Supply Current of 0.3 μA, Longer Battery Life and Downsizing
- Requiring Only Three External Capacitors and Suitable for Space-saving Mounting for the Smaller Packages

KEY SPECIFICATIONS

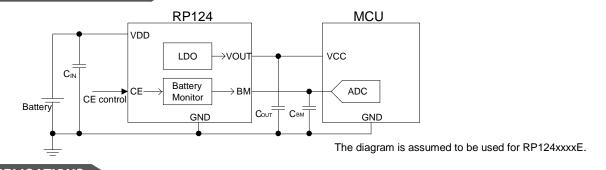
LDO Section

- Input Voltage Range: 1.7 V to 5.5 V
- Supply Current: Typ. 0.2 µA
- Output Voltage Accuracy: ±0.8%
- Output Current: 100 mA
- Ceramic Capacitor Compatible: 1.0 µF or more

BM Section

- Output Voltage: V_{IN}/3 (RP124xxx3x) V_{IN}/4 (RP124xxx4x)
- Supply Current: Typ. 0.1 µA
- Ceramic Capacitor Compatible: 0.1 µF to 0.22 µF

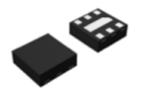




APPLICATIONS

- Battery powered IoT devices
- Energy harvesting devices
- Low power wireless communication modules including: Bluetooth® LE, Zigbee, and LPWA
- Low power consumption CPUs, memories, and sensors

PACKAGES





DFN1212-6 1.2 mm x 1.2 mm x 0.4 mm

SOT-23-5 2.9 mm x 2.8 mm x 1.1 mm

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SELECTION GUIDE

The LDO set output voltage, the divided ratio of BM output voltage, the CE pin function and the auto-discharge function are user-selectable options.

Selection Guide

| Product Name | Package | Quantity per Reel | Pb Free | Halogen Free |
|------------------|-----------|-------------------|---------|--------------|
| RP124Lxx#*-TR | DFN1212-6 | 5,000 pcs | Yes | Yes |
| RP124Nxx#*-TR-FE | SOT-23-5 | 3,000 pcs | Yes | Yes |

xx: Specify the LDO set output voltage (V_{SET}).

1.2 V (12) / 1.5 V (15) / 1.8 V (18) / 2.1 V (21) / 2.2 V (22) / 2.3 V (23) / 2.4 V (24) / 2.5 V (25) / 2.7 V (27) / 2.8 V (28) / 3.0 V (30) / 3.1 V (31) / 3.3 V (33) / 3.6 V (36) Contact Ricoh sales representatives for other voltages.

#: Specify the divided ratio of BM output voltage.

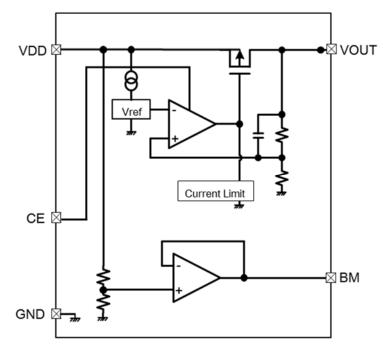
- 3: VIN/3
- 4: V_{IN}/4

*: Specify the CE pin and the auto-discharge option.

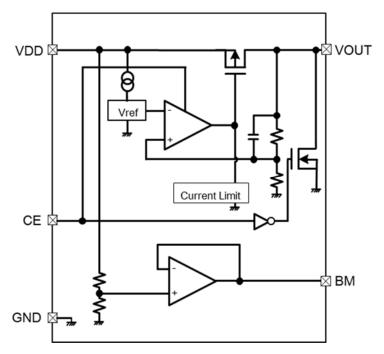
| * | CE pin | Auto-discharge | |
|---|---|----------------|-----|
| Б | Controlling I DO with the CE pin (Active high) | LDO | No |
| В | Controlling LDO with the CE pin (Active-high) | BM | No |
| | Controlling I DO with the CE pin (Active high) | LDO | Yes |
| D | D Controlling LDO with the CE pin (Active-high) | | No |
| | | LDO | No |
| E | Controlling BM with the CE pin (Active-high) | BM | Yes |

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BLOCK DIAGRAMS

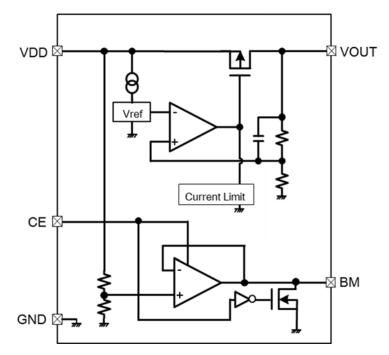


RP124xxxxB Block Diagram



RP124xxxxD Block Diagram

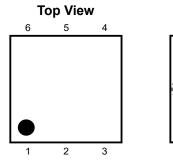
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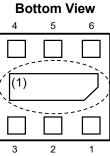


RP124xxxxE Block Diagram

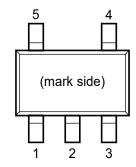
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PIN DESCRIPTIONS





RP124L (DFN1212-6) Pin Configuration



RP124N (SOT-23-5) Pin Configuration

RP124L (DFN1212-6) Pin Description

| Pin No. | Symbol | Description | |
|---------|--------|-------------------------------|--|
| 1 | VOUT | Output Pin | |
| 2 | GND | Ground Pin | |
| 3 | BM | Battery Monitoring Output Pin | |
| 4 | CE | Chip Enable Pin, Active-high | |
| 5 | NC | No Connection | |
| 6 | VDD | Input Pin | |

RP124N (SOT-23-5) Pin Description

| Symbol | Description |
|--------|----------------------------------|
| VDD | Input Pin |
| GND | Ground Pin |
| CE | Chip Enable Pin, Active-high |
| BM | Battery Monitoring Output Pin |
| VOUT | Output Pin |
| | Symbol VDD GND CE BM |

⁽¹⁾ The tab on the bottom of the package enhances thermal performance and is electrically connected to GND (substrate level). It is recommended that the tab be connected to the ground plane on the board, or otherwise be left floating.



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ABSOLUTE MAXIMUM RATINGS

Absolute Maximum Ratings

| Symbol | | Item | Rating | Unit |
|-----------------|---|---------------|-------------------------------|------|
| VIN | Input Voltage | | -0.3 to 6.5 | V |
| V _{CE} | CE Pin Voltage | 9 | -0.3 to 6.5 | V |
| Vout | VOUT Pin Volt | age | -0.3 to V _{IN} + 0.3 | V |
| VBM | BM Pin Voltage | e | -0.3 to V _{IN} + 0.3 | V |
| IOUT | Output Current | | 130 | mA |
| D- | Power DFN1212-6 (JEDEC STD. 51-7 Test Land Pattern) | | 850 | mW |
| PD | Dissipation ⁽¹⁾ SOT-23-5 (JEDEC STD. 51-7 Test Land Pattern) | | 660 | mW |
| Tj | Junction Temperature Range | | -40 to 125 | °C |
| Tstg | Storage Temp | erature Range | -55 to 125 | °C |

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause permanent damage and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS

Recommended Operating Conditions

| Symbol | Item | Rating | Unit | |
|--------|-----------------------|------------|------------|----|
| Max | | RP124xxx3x | 1.7 to 5.5 | V |
| Vin | Input Voltage | RP124xxx4x | 2.4 to 5.5 | v |
| Та | Operating Temperature | | -40 to 85 | °C |

RECOMMENDED OPERATING CONDITIONS

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

⁽¹⁾ Refer to POWEWR DISSIPATION for detailed information.

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ELECTRICAL CHARACTERISTICS

 $V_{IN} = V_{SET} + 1.0 \text{ V}, I_{OUT} = 1.5 \text{ mA}, C_{IN} = C_{OUT} = 1.0 \mu\text{F}$, unless otherwise noted. The specifications surrounded by ______ are guaranteed by design engineering at -40°C ≤ Ta ≤ 85°C.

| RP124x B | RP124x Electrical Characteristics: LDO Section(Ta = 25°C) | | | | | | |
|-------------------|---|--|--------------------------------------|------------------|------|-----------------------|------|
| Symbol | Parameters | Test Cond | ditions | Min. | Тур. | Max. | Unit |
| | | V _{SET} > 2.0 V | | x0.992 x0.987 | | x1.008 x1.013 | V |
| Vout | Output Voltage | $V_{\text{SET}} \leq 2.0 \text{ V}$ | | -16 -26 | | 16 26 | mV |
| Іоит | Output Current | | | 100 | | | mA |
| | Output Voltage | | V _{SET} > 2.0 V | -1 | | 1 | % |
| ΔV out | Deviation When Switching Mode | 1 µA ≤ louт ≤ louтн | $V_{\text{SET}} \leq 2.0 \ \text{V}$ | -20 | | 20 | mV |
| ΔVουτ /ΔΙουτ | Load Regulation | $1.5 \text{ mA} \le I_{OUT} \le 100 \text{ r}$ | mA | -40 | 2 | 40 | mV |
| V _{DIF} | Dropout Voltage | I _{OUT} = 100 mA | | | | duct-spe haracteri | |
| lss | Supply Current | Vce = Vin, Iout = 0 m/ | Δ | | 0.2 | 0.42 | μΑ |
| | | | Υ. | | | 0.5 | μA |
| Іоитн | Fast Mode Switching Current | $I_{OUT} =$ From Light Loa $V_{IN} = 5.0 V$ | ad to Heavy Load, | | 0.5 | | mA |
| IOUTL | Low Power Mode Switching Current | Iout = From Heavy Lo V _{IN} = 5.0 V | oad to Light Load, | 0.08 | | | mA |
| ΔV_{OUT} | Line Regulation | V_{SET} + 0.5 V \leq V_{IN} \leq 5.5 V | | | 0.02 | 0.2 | %/V |
| lsc | Short Current Limit | V _{OUT} = 0 V | | | 65 | | mA |
| Vсен | CE Pin Input Voltage, high | RP124xxxxB/D | | 1.0 | | | V |
| V _{CEL} | CE Pin Input Voltage, low | RP124xxxxB/D | | | | 0.4 | V |
| R _{DISN} | Auto-discharge NMOS On-resistance | $V_{IN} = 4.0 \text{ V}, \text{ V}_{CE} = 0 \text{ V}$ | /, RP124xxxxD | | 50 | | Ω |

All test items listed under Electrical Characteristics are done under the pulse load condition Tj \approx Ta = 25°C.

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ELECTRICAL CHARACTERISTICS (continued)

The specifications surrounded by \square are guaranteed by design engineering at $-40^{\circ}C \le Ta \le 85^{\circ}C$.

| . | | | Vou | т [V] | | | v | r\/1 |
|-----------------|-----------|-------|-------------------|-------|-------|----------------------|-------|---------|
| Product Name | Ta = 25°C | | −40°C ≤ Ta ≤ 85°C | | | V _{DIF} [V] | | |
| Name | Min. | Тур. | Max. | Min. | Тур. | Max. | Тур. | Max. |
| RP124x12xx | 1.184 | 1.200 | 1.216 | 1.174 | 1.200 | 1.226 | 0.640 | 0.975 |
| RP124x15xx | 1.484 | 1.500 | 1.516 | 1.474 | 1.500 | 1.526 | 0.410 | 0.660 |
| RP124x18xx | 1.784 | 1.800 | 1.816 | 1.774 | 1.800 | 1.826 | 0.230 | 0.380 |
| RP124x21xx | 2.084 | 2.100 | 2.116 | 2.073 | 2.100 | 2.127 | 0.150 | 0.285 |
| RP124x22xx | 2.183 | 2.200 | 2.217 | 2.172 | 2.200 | 2.228 | | |
| RP124x23xx | 2.282 | 2.300 | 2.318 | 2.271 | 2.300 | 2.329 | 0.130 | 0.230 |
| RP124x24xx | 2.381 | 2.400 | 2.419 | 2.369 | 2.400 | 2.431 | | |
| RP124x25xx | 2.480 | 2.500 | 2.520 | 2.468 | 2.500 | 2.532 | 0.110 | 0.190 |
| RP124x27xx | 2.679 | 2.700 | 2.721 | 2.665 | 2.700 | 2.735 | 0.110 | 0.180 |
| RP124x28xx | 2.778 | 2.800 | 2.822 | 2.764 | 2.800 | 2.836 | | |
| RP124x30xx | 2.976 | 3.000 | 3.024 | 2.961 | 3.000 | 3.039 | 0.100 | 0.160 |
| RP124x31xx | 3.076 | 3.100 | 3.124 | 3.060 | 3.100 | 3.140 | | |
| RP124x33xx | 3.274 | 3.300 | 3.326 | 3.258 | 3.300 | 3.342 | 0.000 | 0 1 4 5 |
| RP124x36xx | 3.572 | 3.600 | 3.628 | 3.554 | 3.600 | 3.646 | 0.090 | 0.145 |

RP124x Product-specific Electrical Characteristics: LDO Section

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ELECTRICAL CHARACTERISTICS (continued)

 C_{IN} = 1.0 $\mu F,\,C_{\text{BM}}$ = 0.22 $\mu F,$ unless otherwise noted.

The specifications surrounded by \square are guaranteed by design engineering at $-40^{\circ}C \le Ta \le 85^{\circ}C$.

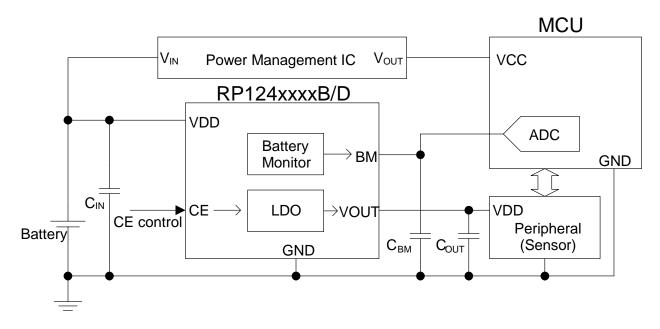
| RP124x | RP124x Electrical Characteristics: Battery Monitor Section (Ta = 25°C) | | | | | | | |
|-------------------|---|--|--|---|--------------------|-----------------------|------|---|
| Symbol | Parameters | Test Con | ditions | Min. | Тур. | Max. | Unit | |
| | | | 1.7 V ≤ V _{IN} ≤ 5.5 V, | V _{IN} /3-20 | V _{IN} /3 | V _{IN} /3+20 | | |
| Maria | | | RP124xxx3x | V _{IN} /3-25 | V _{IN} /3 | VIN/3+25 | m\/ | |
| VBM | Output Voltage | −10 μA ≤ I _{BM} ≤ 10 μA | $2.4 \text{ V} \le \text{V}_{\text{IN}} \le 5.5 \text{ V},$ | V _{IN} /4-20 | V _{IN} /4 | V _{IN} /4+20 | mV | |
| | | | RP124xxx4x | V _{IN} /4-25 | V _{IN} /4 | V _{IN} /4+25 | | |
| | | 1.7 V ≤ V _{IN} ≤ 5.5 V, R | 1.7 V ≤ V _{IN} ≤ 5.5 V, RP124xxx3x | | | 10 | | |
| Івм | Output Current | $2.4 \text{ V} \le \text{V}_{\text{IN}} \le 5.5 \text{ V}, \text{ R}$ | P124xxx4x | -10 | | 10 | μA | |
| I _{SSBM} | Supply Current | $V_{\text{IN}} = V_{\text{CE}} = 3.6 \text{ V} \text{ , } I_{\text{BN}}$ | $V_{\text{IN}} = V_{\text{CE}} = 3.6 \ \text{V}$, $I_{\text{BM}} = 0 \ \mu\text{A}$ | | 0.1 | 0.2 | μA | |
| Manual | CE Pin Input | 1.7 V ≤ V _{IN} ≤ 5.5 V, R | 1.7 V ≤ V _{IN} ≤ 5.5 V, RP124xxx3E | | | | V | |
| Vсенвм | Voltage, high | $2.4 \text{ V} \le \text{V}_{\text{IN}} \le 5.5 \text{ V}, \text{ R}$ | P124xxx4E | 1.0 | | | V | |
| N/ | CE Pin Input | 1.7 V ≤ V _{IN} ≤ 5.5 V, R | 1.7 V ≤ V _{IN} ≤ 5.5 V, RP124xxx3E | | | 0.4 | V | |
| Vcelbm | Voltage, low | 2.4 V ≤ V _{IN} ≤ 5.5 V, RP124xxx4E | | Voltage, low $2.4 \text{ V} \le \text{V}_{IN} \le 5.5 \text{ V}$, RP124xxx4E | | | 0.4 | V |
| Rdisnbm | Auto-discharge NMOS On- resistance | $V_{\text{IN}} = 4.0 \text{ V}, \text{ V}_{\text{CE}} = 0 \text{ V}$ | , RP124xxxxE | | 50 | | Ω | |

All test items listed under Electrical Characteristics are done under the pulse load condition Tj \approx Ta = 25°C.

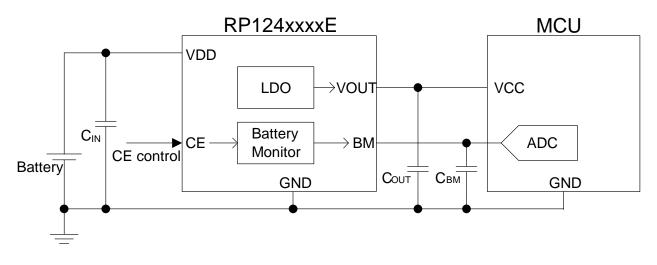
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APPLICATION INFORMATION

TYPICAL APPLICATION

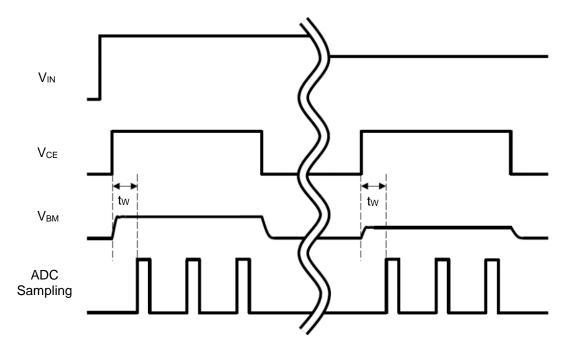


RP124xxxxB/D Typical Application Circuit



RP124xxxxE Typical Application Circuit

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Timing Chart Example of RP124xxxxE Circuit

The above diagram shows the example of using the RP124xxxxE typical application circuit and its timing chart. Connecting BM pin and ADC input pin of MCU enables monitoring the battery voltage. Controlling the start-up and stop of Battery Monitor with CE pin by the timing based on the ADC sampling reduces power consumption of the entire system. When monitoring the battery voltage, set the waiting time (tw) in order to stabilize waveform after the CE input voltage is set to "H". It is recommended to set tw \geq 10 ms for this product.

Notes on External Components

- Phase compensation is provided to secure stable operation even when the load current is varied. For this purpose, use a 1.0-µF or more output capacitor (C_{OUT}) between the VOUT and GND pins, and a 0.1-µF to 0.22-µF capacitor (C_{BM}) between the BM and GND pins with shortest-distance wiring. In case of using a tantalum type capacitor with a large ESR (Equivalent Series Resistance), the output might become unstable. Evaluate your circuit including consideration of frequency characteristics.
- Connect a 1.0-µF or more input capacitor (C_{IN}) between the VDD and GND pins with shortest-distance wiring.

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TECHNICAL NOTES

The performance of a power source circuit using this device is highly dependent on a peripheral circuit. A peripheral component or the device mounted on PCB should not exceed its rated voltage, rated current or rated power. When designing a peripheral circuit, please be fully aware of the following points.

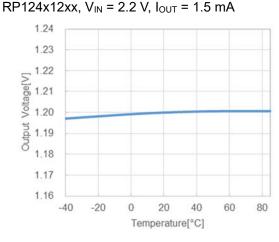
- The high impedance of the wirings may result in noise pickup and unstable operation of the device. Reduce the impedance of the VDD and GND wirings.
- When an intermediate voltage other than V_{IN} or GND is input to the CE pin, a supply current may be increased with a through current of a logic circuit in the IC. The CE pin is neither pulled up nor pulled down, therefore an operation is not stable at open.

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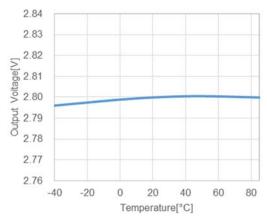
TYPICAL CHARACTERISTICS

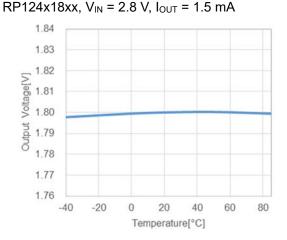
Typical Characteristics are intended to be used as reference data; they are not guaranteed.

1) LDO Output Voltage vs. Temperature (C_{IN} = Ceramic 1.0 μ F, C_{OUT} = Ceramic 1.0 μ F)

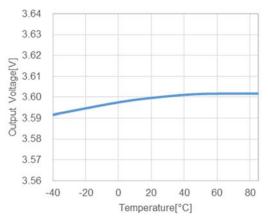


RP124x28xx, V_{IN} = 3.8 V, I_{OUT} = 1.5 mA

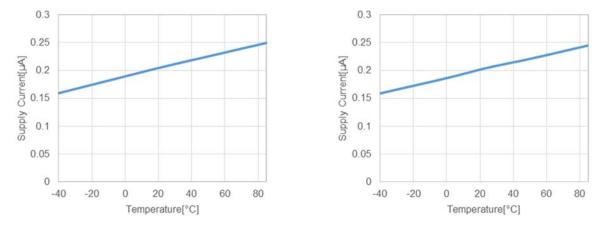




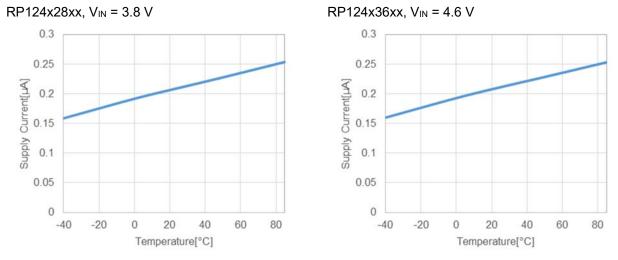
RP124x36xx, V_{IN} = 4.6 V, I_{OUT} = 1.5 mA



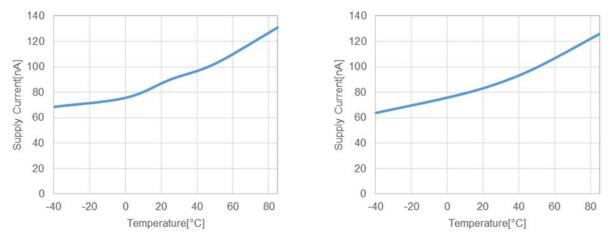
2) LDO Supply Current vs. Temperature (C_{IN} = Ceramic 1.0 μ F, C_{OUT} = Ceramic 1.0 μ F) RP124x12xx, V_{IN} = 2.2 V RP124x18xx, V_{IN} = 2.8 V



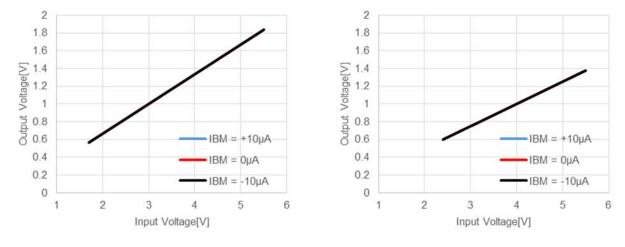
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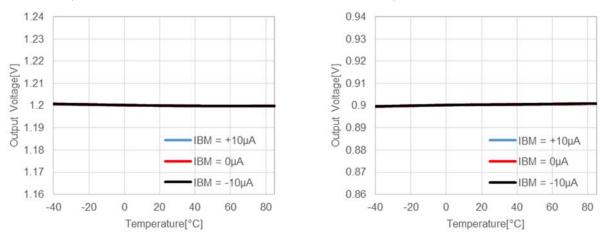
3) BM Supply Current vs. Temperature (C_{IN} = Ceramic 1.0 µF, C_{BM} = Ceramic 0.1 µF) RP124xxx3x, V_{IN} = 3.6 V RP124xxx4x, V_{IN} = 3.6 V



4) BM Output Voltage vs. Input Voltage (C_{IN} = Ceramic 1.0 μ F, C_{BM} = Ceramic 0.1 μ F, Ta = 25°C) RP124xxx3x RP124xxx4x

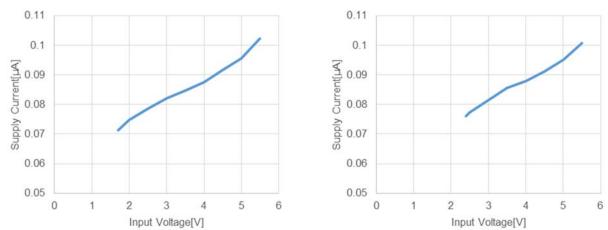


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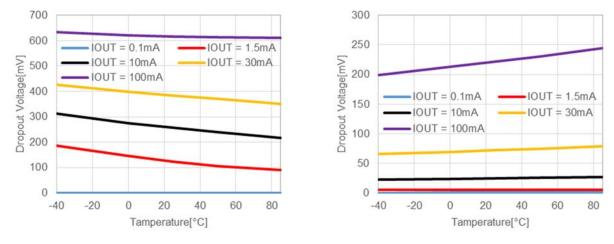


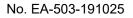
5) BM Output Voltage vs. Temperature (C_{IN} = Ceramic 1.0 μ F, C_{BM} = Ceramic 0.1 μ F) RP124xxx3x, V_{IN} = 3.6 V RP124xxx4x, V_{IN} = 3.6 V

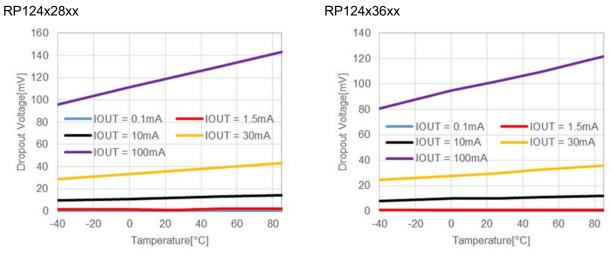
6) BM Supply Current vs. Input Voltage (C_{IN} = Ceramic 1.0 μF, C_{BM} = Ceramic 0.1 μF, Ta = 25°C) RP124xxx3x RP124xxx4x



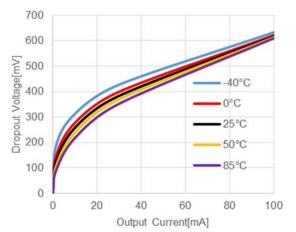
7) LDO Dropout Voltage vs. Temperature (C_{IN} = Ceramic 1.0 μ F, C_{OUT} = Ceramic 1.0 μ F) RP124x12xx RP124x18xx

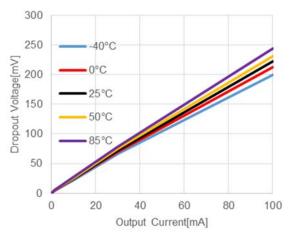




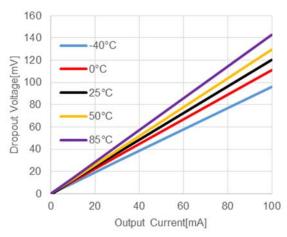


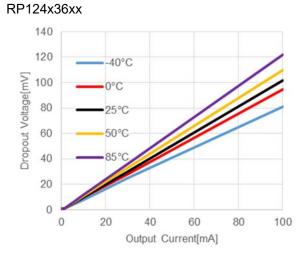
8) LDO Dropout Voltage vs. Output Current (C_{IN} = Ceramic 1.0 μF, C_{OUT} = Ceramic 1.0 μF) RP124x12xx RP124x18xx



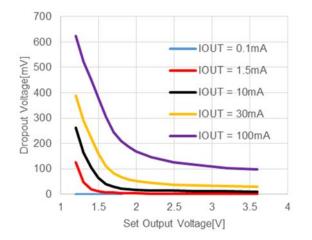






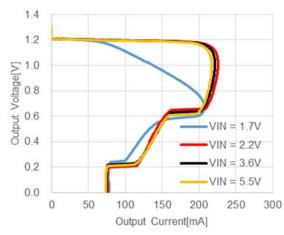


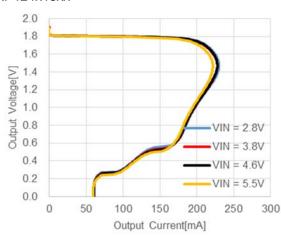
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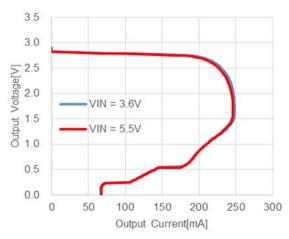
9) LDO Dropout Voltage vs. Set Output Voltage (C_{IN} = Ceramic 1.0 µF, C_{OUT} = Ceramic 1.0 µF, Ta = 25°C)

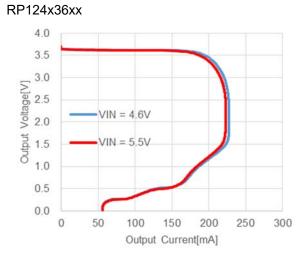
10) LDO Output Voltage vs. Output Current (C_{IN} = Ceramic 1.0 µF, C_{OUT} = Ceramic 1.0 µF, Ta = 25°C) RP124x12xx RP124x18xx



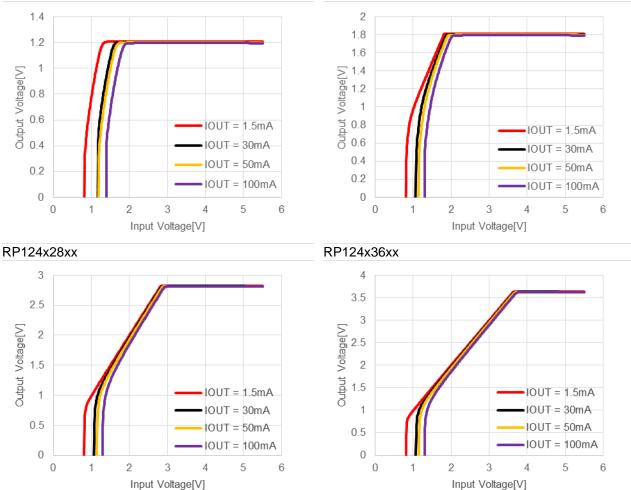


RP124x28xx



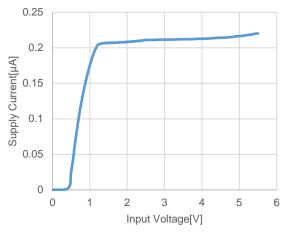


No. EA-503-191025

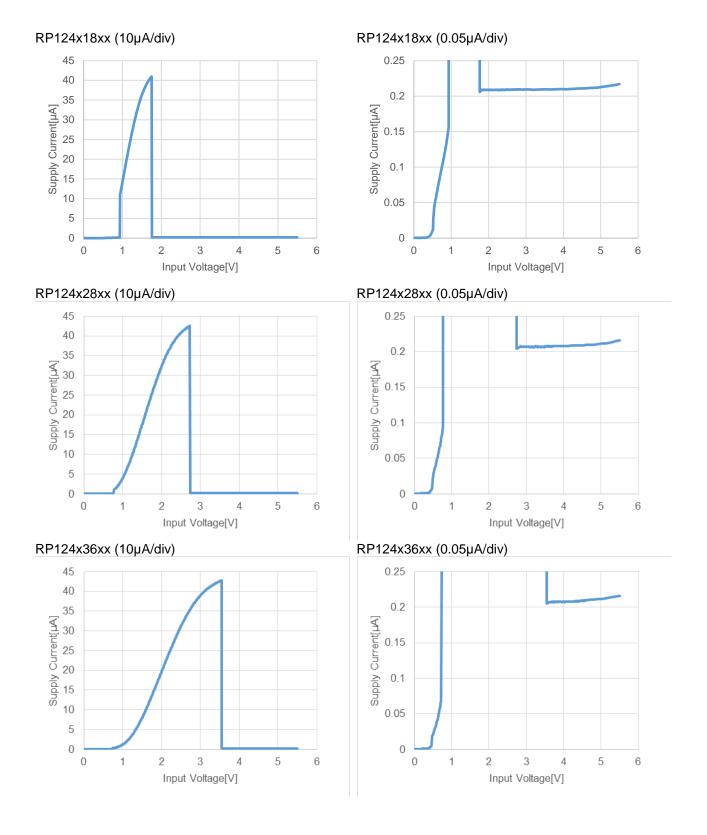


11) LDO Output Voltage vs. Input Voltage (C_{IN} = Ceramic 1.0 μ F, C_{OUT} = Ceramic 1.0 μ F, Ta = 25°C) RP124x12xx RP124x18xx

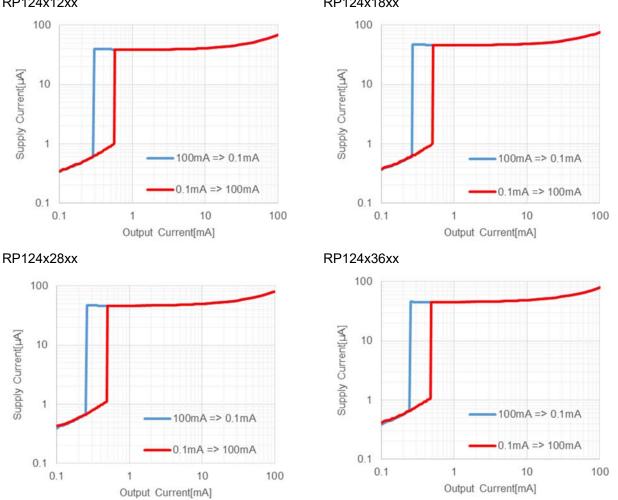
12) LDO Supply Current vs. Input Voltage (C_{IN} = Ceramic 1.0 μ F, C_{OUT} = Ceramic 1.0 μ F, Ta = 25°C) RP124x12xx



No. EA-503-191025

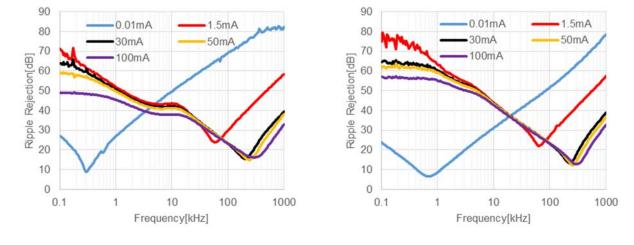


No. EA-503-191025

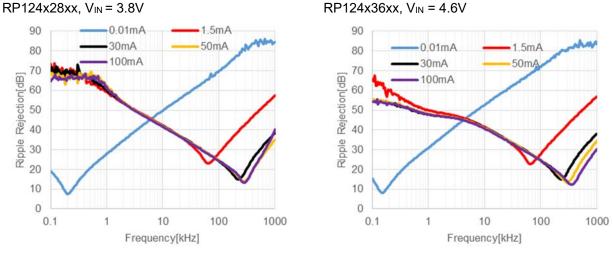


13) LDO Supply Current vs. Output Current (C_{IN} = Ceramic 1.0 μ F, C_{OUT} = Ceramic 1.0 μ F, Ta = 25°C) RP124x12xx RP124x18xx

14) Ripple Rejection vs. Frequency (C_{IN} = none, C_{OUT} = Ceramic 1.0 µF, Ta = 25°C) RP124x12xx, V_{IN} = 2.2 V RP124x18xx, V_{IN} = 2.8 V



No. EA-503-191025

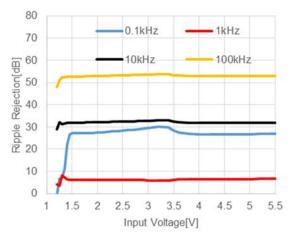


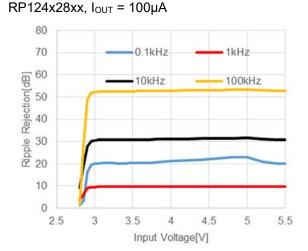
80

70

60

15) Ripple Rejection vs. Input Voltage (C_{IN} = none, C_{OUT} = Ceramic 1.0 μF, Ta = 25°C) RP124x18xx, I_{OUT} = 100 μA RP124x12xx, Iout = 100 µA





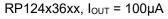


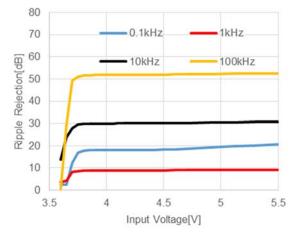
0.1kHz

10kHz

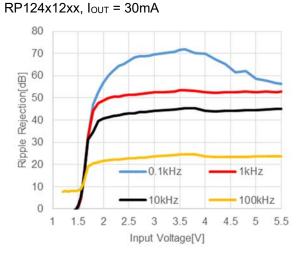
1kHz

100kHz

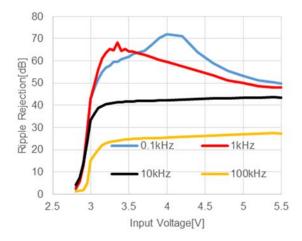




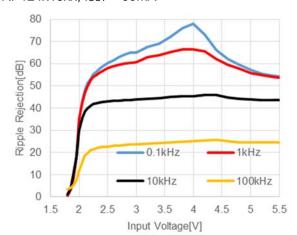
No. EA-503-191025



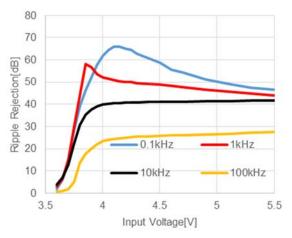
RP124x28xx, I_{OUT} = 30mA



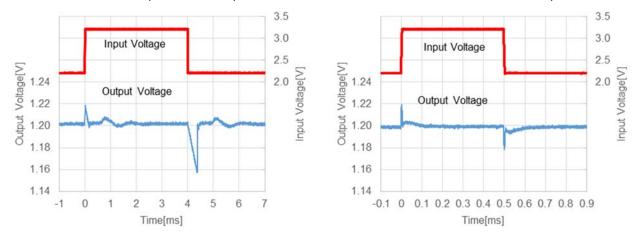
RP124x18xx, Iout = 30mA

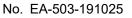


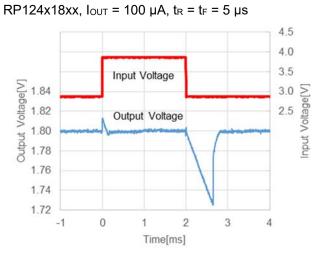


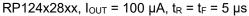


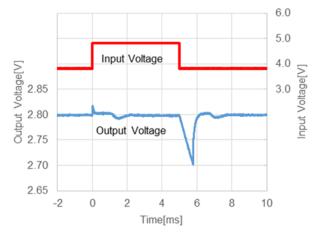
16) LDO Input Transient Response (C_{IN} = Ceramic 0.1 μ F, C_{OUT} = Ceramic 1.0 μ F, Ta = 25°C) RP124x12xx, I_{OUT} = 100 μ A, t_R = t_F = 5 μ s RP124x12xx, I_{OUT} = 30 mA, t_R = t_F = 5 μ s



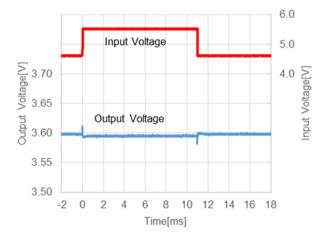


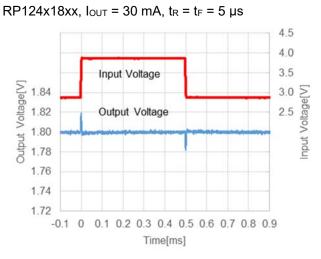




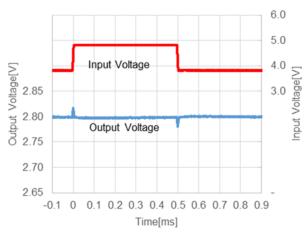


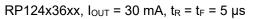


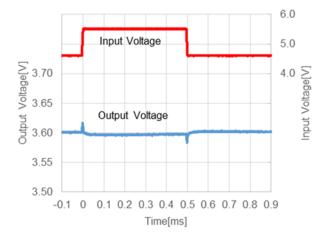




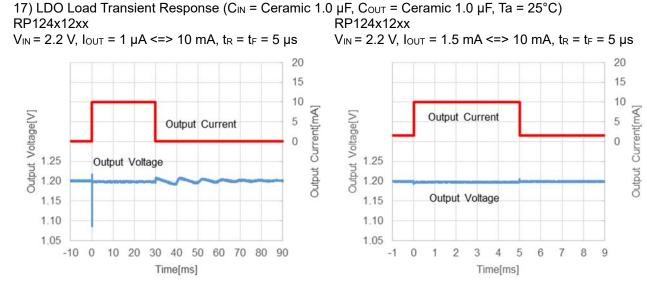
RP124x28xx, I_{OUT} = 30 mA, t_R = t_F = 5 µs



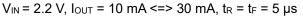


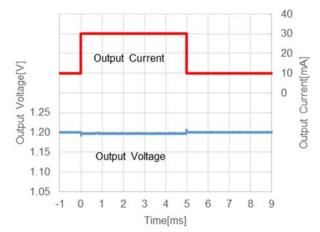


No. EA-503-191025

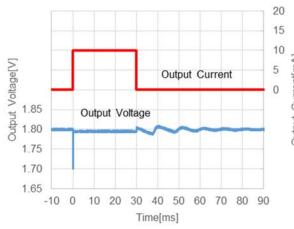


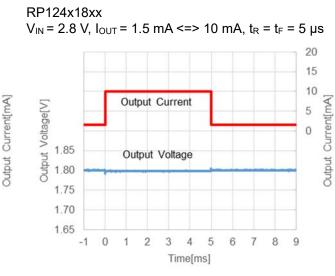
RP124x12xx





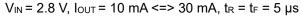
RP124x18xx V_{IN} = 2.8 V, I_{OUT} = 1 μ A <=> 10 mA, t_R = t_F = 5 μ s

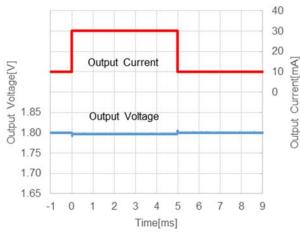




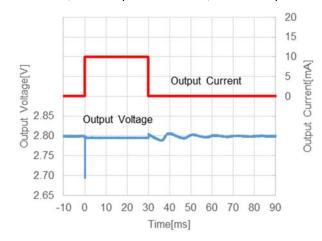
No. EA-503-191025

RP124x18xx

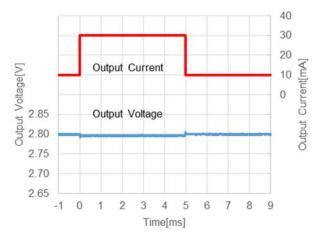




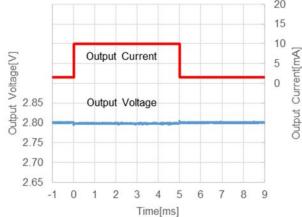
RP124x28xx V_{IN} = 3.8 V, I_{OUT} = 1 μ A <=> 10 mA, t_R = t_F = 5 μ s



RP124x28xx V_{IN} = 3.8 V, I_{OUT} = 10 mA <=> 30 mA, t_R = t_F = 5 µs

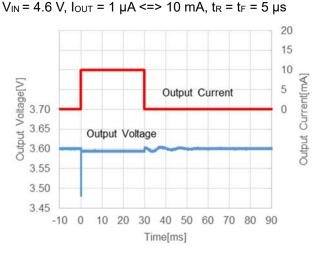


RP124x28xx V_{IN} = 3.8 V, I_{OUT} = 1.5 mA <=> 10 mA, t_R = t_F = 5 µs 20

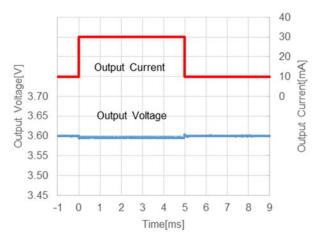


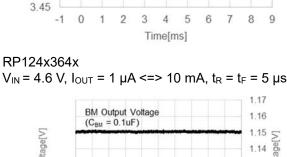
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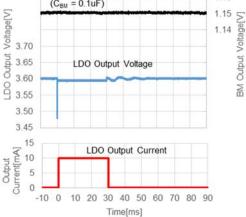
RP124x36xx

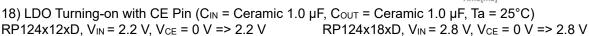


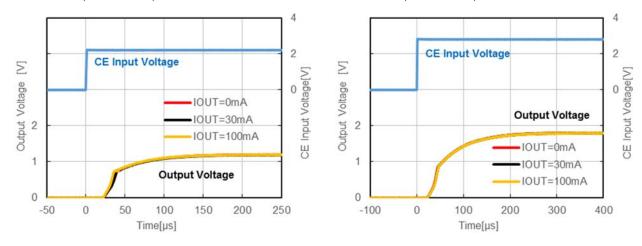
RP124x36xx V_{IN} = 4.6 V, I_{OUT} = 10 mA <=> 30 mA, $t_R = t_F = 5 \ \mu s$











RP124x36xx V_{IN} = 4.6 V, I_{OUT} = 1.5 mA <=> 10 mA, $t_R = t_F = 5 \ \mu s$ 20

Output Current

Output Voltage

Output Voltage[V]

3.70 3.65

3.60

3.55

3.50

10

5

0

Output Current[mA]

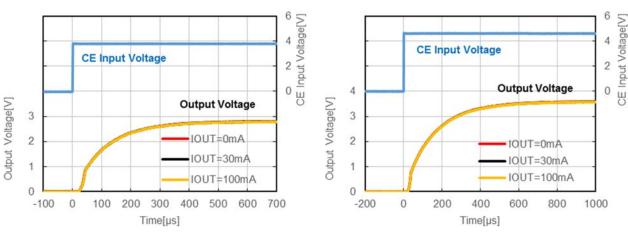
4

2

0

CE Input Voltage[V]

No. EA-503-191025



19) LDO Turning-off with CE Pin (C_{IN} = Ceramic 1.0 µF, C_{OUT} = Ceramic 1.0 µF, Ta = 25°C) RP124x12xD, V_{IN} = 2.2 V, V_{CE} = 2.2 V => 0 V RP124x18xD, V_{IN} = 2.8 V, V_{CE} = 2.8 V => 0 V

Σ

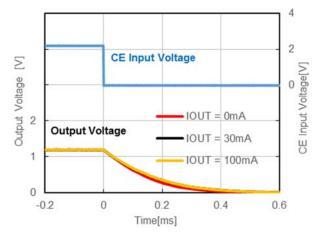
Output Voltage

2

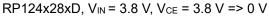
1

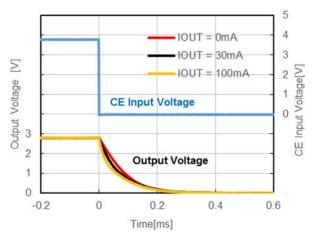
0

Output Voltage



RP124x28xD, V_{IN} = 3.8 V, V_{CE} = 0 V => 3.8 V





0 0.6 -0.2 0.2 Time[ms] RP124x36xD, V_{IN} = 4.6 V, V_{CE} = 4.6 V => 0 V

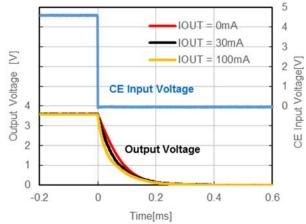
CE Input Voltage

IOUT = 0mA

IOUT = 30mA

IOUT = 100mA

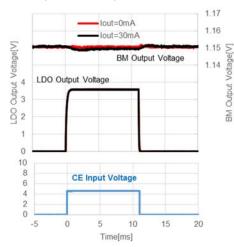
0.4



RP124x36xD, V_{IN} = 4.6 V, V_{CE} = 0 V => 4.6 V

No. EA-503-191025

RP124x364D, V_{IN} = 4.6 V, V_{CE} = 0 V <=> 4.6 V



20) BM Turning-on/off with CE Pin (C_{IN} = Ceramic 1.0 μ F, C_{BM} = Ceramic 0.1 μ F, 0.22 μ F, Ta = 25°C) RP124xxx3x, V_{IN} = 3.6 V, V_{CE} = 0 V <=> 3.6 V RP124xxx4x, V_{IN} = 3.6 V, V_{CE} = 0 V <=> 3.6 V

> Output Voltage[V] 1.5

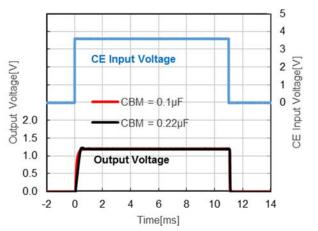
1.0

0.5

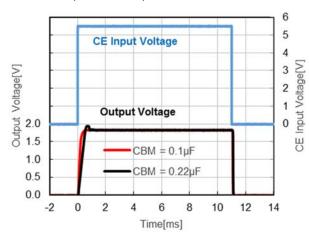
0.0

-2

0







RP124xxx4x, V_{IN} = 5.5 V, V_{CE} = 0 V <=> 5.5 V

2

Output Voltage

4

CE Input Voltage

 $CBM = 0.1 \mu F$

CBM = 0.22µF

6

Time[ms]

10

8

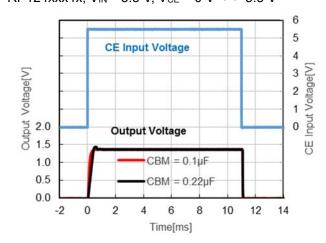
12

14

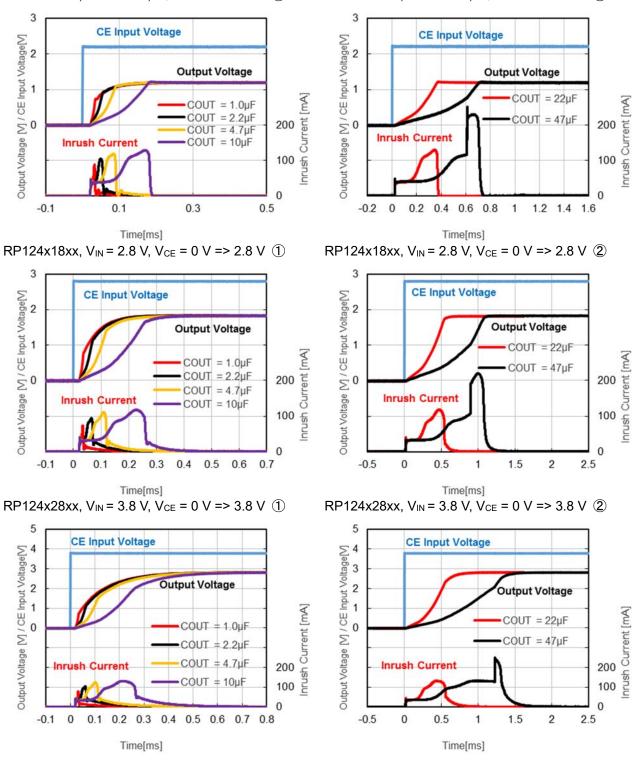
5

4 3

CE Input Voltage[V]

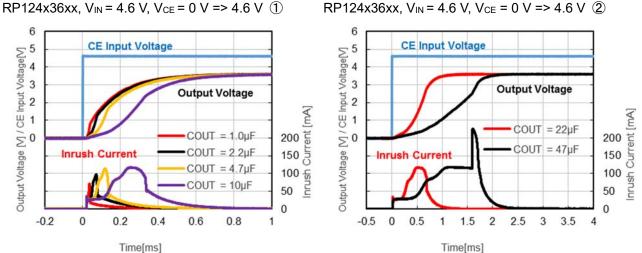


No. EA-503-191025

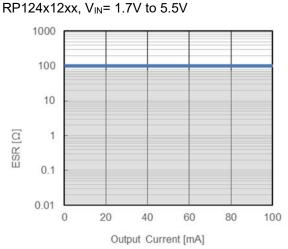


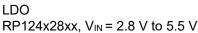
21) Inrush Current at CE Pin's Activation (C_{IN} = Ceramic 0.1 μ F, Ta = 25°C) RP124x12xx, V_{IN} = 2.2 V, V_{CE} = 0 V => 2.2 V ① RP124x12xx, V_{IN} = 2.2 V, V_{CE} = 0 V => 2.2 V ②

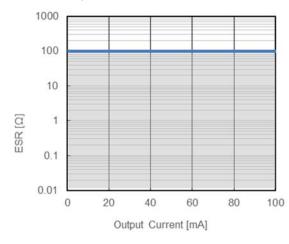
No. EA-503-191025



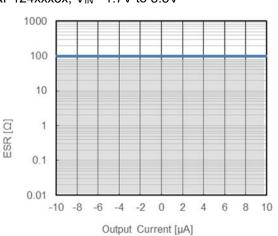
22) ESR vs. Output Current (C_{IN} = Ceramic 1.0 μ F, C_{OUT} = Ceramic 1.0 μ F, C_{BM} = Ceramic 0.1 μ F) Measuring Frequency : 10 Hz to 2 MHz, Ambient Temperature : -40°C to 5°C LDO BM



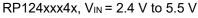


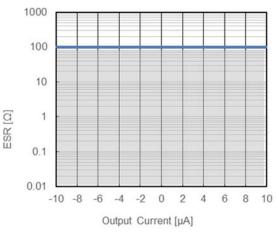


RP124xxx3x, V_{IN}= 1.7V to 5.5V

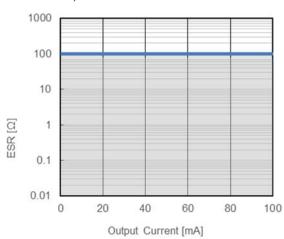








No. EA-503-191025



LDO RP124x36xx, V_{IN} = 3.6 V to 5.5 V

POWER DISSIPATION

DFN1212-6

Ver. A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

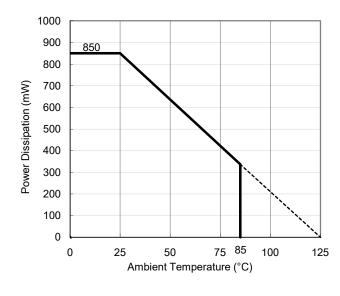
| ltem | Measurement Conditions |
|------------------|--|
| Environment | Mounting on Board (Wind Velocity = 0 m/s) |
| Board Material | Glass Cloth Epoxy Plastic (Four-Layer Board) |
| Board Dimensions | 76.2 mm × 114.3 mm × 0.8 mm |
| Copper Ratio | Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square |
| Through-holes | φ 0.2 mm × 14 pcs |

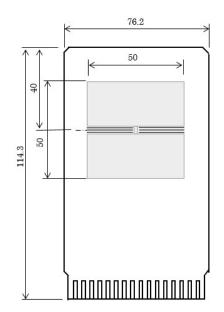
Measurement Result

| Measurement Result | (Ta = 25°C, Tjmax = 125°C) |
|--|----------------------------|
| Item | Measurement Result |
| Power Dissipation | 850 mW |
| Thermal Resistance (θ ja) | θja = 117°C/W |
| Thermal Characterization Parameter (ψjt) | ψjt = 50°C/W |

θja: Junction-to-Ambient Thermal Resistance

wit: Junction-to-Top Thermal Characterization Parameter





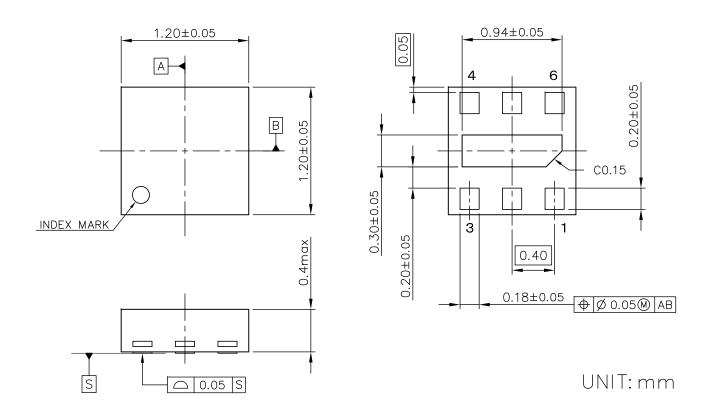
Power Dissipation vs. Ambient Temperature

Measurement Board Pattern

i

DFN1212-6

Ver. B



DFN1212-6 Package Dimensions

^{*} The tab on the bottom of the package is substrate level (GND). It is recommended that the tab be connected to the ground plane on the board, or otherwise be left floating.



POWER DISSIPATION

SOT-23-5

Ver. A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

| ltem | Measurement Conditions | |
|------------------|--|--|
| Environment | Mounting on Board (Wind Velocity = 0 m/s) | |
| Board Material | Glass Cloth Epoxy Plastic (Four-Layer Board) | |
| Board Dimensions | 76.2 mm × 114.3 mm × 0.8 mm | |
| Copper Ratio | Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square | |
| Through-holes | φ 0.3 mm × 7 pcs | |

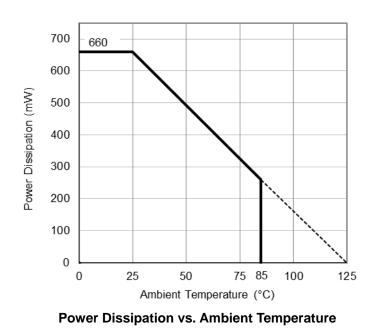
Measurement Result

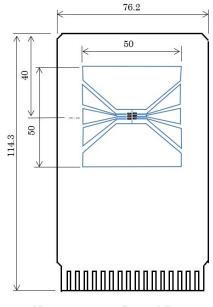
(Ta = 25°C, Tjmax = 125°C)

| Item | Measurement Result |
|--|--------------------|
| Power Dissipation | 660 mW |
| Thermal Resistance (θja) | θja = 150°C/W |
| Thermal Characterization Parameter (ψjt) | ψjt = 51°C/W |

θja: Junction-to-Ambient Thermal Resistance

wjt: Junction-to-Top Thermal Characterization Parameter

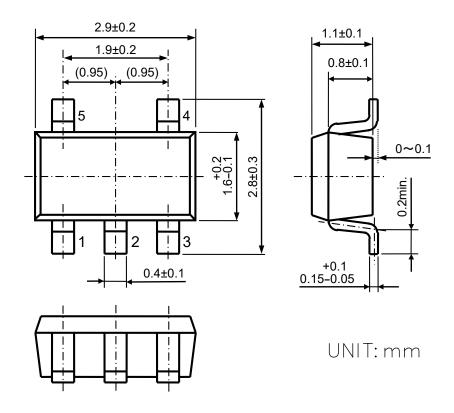


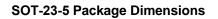


Measurement Board Pattern

SOT-23-5

Ver. A





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